Ref	Hits	Search Query	DBs	Default	Plurals	Time Stamp
#				Operator		
S1	750	257/57.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 09:51
S2	2085	257/59.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 09:52
S3	1555	257/66.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 09:52
S4	2860	257/347.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 09:52
S5 .	2860	257/347.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 10:42
S6	424	257/352.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 11:42
S7	328	257/353.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 09:52
S8	328	257/354.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 10:07
S9	6737	S1 or S2 or S3 or S4 or S6 or S7 or S8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 10:08
S10	237	S6 not S5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 11:44
S11	561	S7 or S8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 11:49

S12	3874	S1 or S2 or S3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 11:49
S13	3391	S12 not S5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:20
S14	2462	source near10 drain near10 separat\$ near10 insulat\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:41
S15	2083	S14 same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:22
S16	951	S15 same channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:28
S17	181	S16 and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:28
S18	9570	source near4 drain near4 separat\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:43
S19	946	S18 near4 (insulat? or dielectric or oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:43
S20	795	S19 same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:44
S21	318	S20 same channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:44
S22	314	S21 not S17	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:49
S23	1	"20020168823".PN.	US-PGPUB	OR	ON	2006/01/08 12:46

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S24	1	"20010036693".PN.	US-PGPUB	OR	ON	2006/01/08 12:46
S25	1	"6593192".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:46
S26	1	"6579750".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:47
S27	1	"6420218".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:47
S28	1	"6437404".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:47
S29	1	"6420218".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:48
S30	1	"6383849".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:48
S31	1	"6274913".PN.	USPAT; USOCR	OR	ON	2006/01/08 12:48
S32	2243	ong.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:50
S33	362	S32 and organic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:50
S34	45	S33 and source and drain	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:52
S35	112	source near7 drain near7 interven\$ near7 (dielectric or insulat\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/08 12:53